

Fig. 1

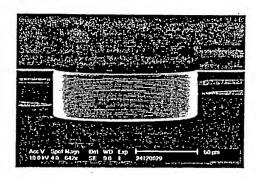


Fig. 2

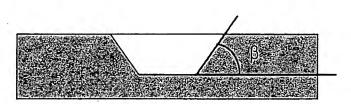
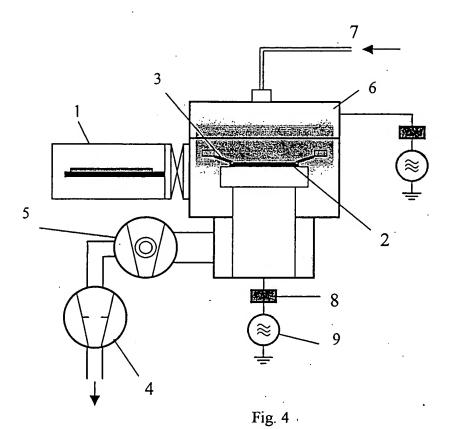


Fig. 3



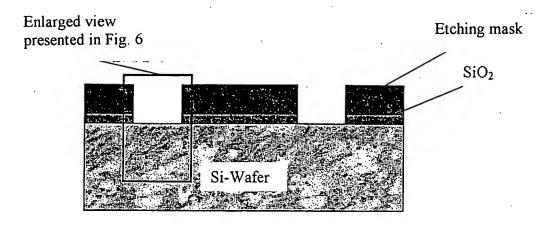


Fig. 5

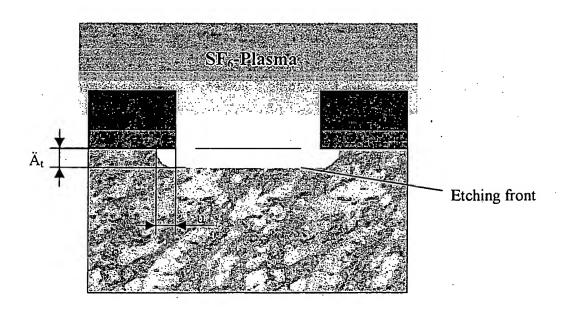
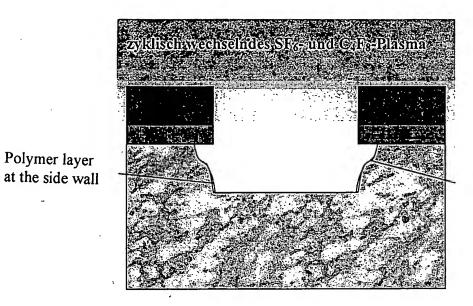


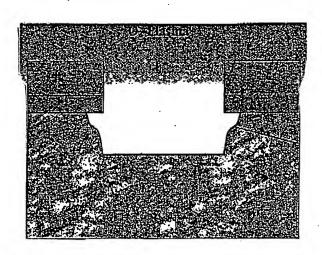
Fig. 6

THE SAME



New way of etching front

Fig. 7



Etching front

Fig. 8

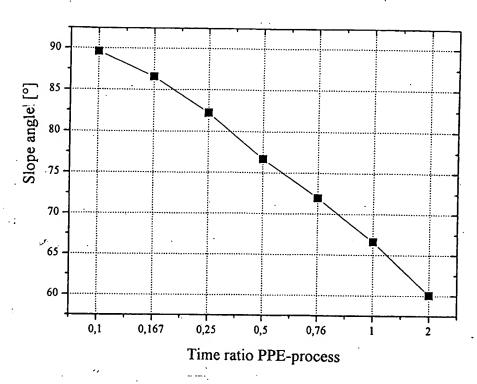


Fig. 9 Dependence of the slope angle of the etched structure from the time ratio Z (t sf6-RIE/tase)

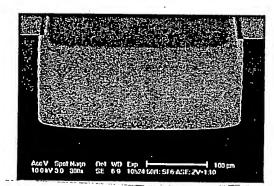


Fig. 10 Structure with slope angle  $\beta = 89^{\circ}$ , etched at Z = 0,1

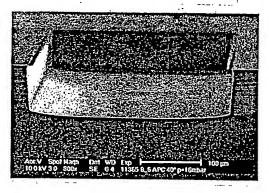


Fig. 12 Structure with slope angle  $\beta = 83^{\circ}$ , etched at Z =

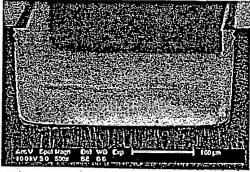


Fig. 11 Structure with slope angle  $\beta = 86^{\circ}$ , etched at Z = 0,167

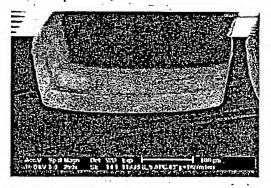


Fig. 13 Structure with slope angle  $\beta = 81^{\circ}$ , etched at Z =

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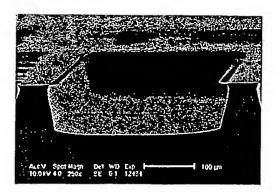


Fig. 14 Structure with slope angle  $\beta = 77^{\circ}$ , etched at Z = 0.5

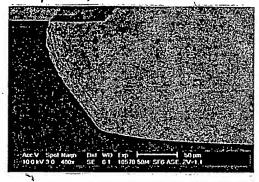


Fig. 16 Structure with slope angle  $\beta = 66^{\circ}$ , etched at Z = 1

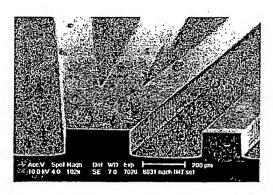


Fig. 18 Embossed tool from silicon

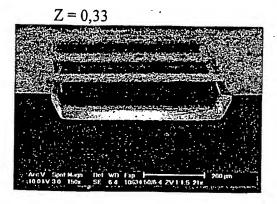


Fig. 15 Structure with slope angle  $\beta = 74^{\circ}$ , etched at Z = 0.67

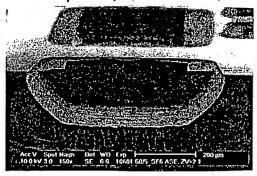
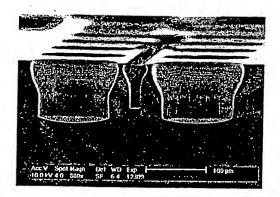


Fig. 17 Structure with slope angle  $\beta = 60^{\circ}$ , etched at Z = 2



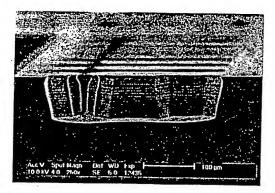


Fig. 19a Silicon structure with y-shaped profile Fig. 19b Silicon structure with y-shaped profile

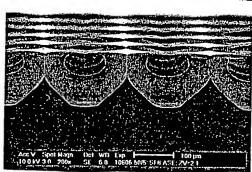


Fig. 20 Silicon structure for liquid storage cells

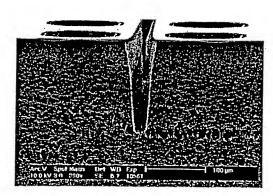


Fig. 21 Trench in silicon with slightly inclined walls

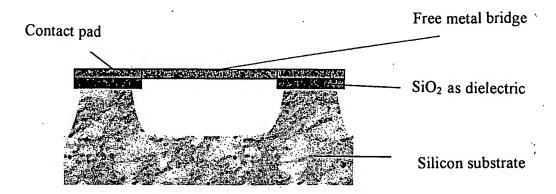


Fig. 22 Metal bridge structure on silicon

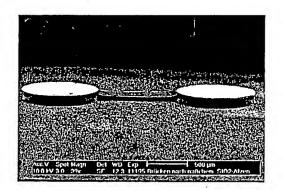


Fig. 23 Cu-bridge structure produced by way of the PPE-process

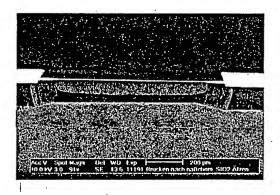


Fig. 24 Cu-bridge laid bare